UN9211/9212/9213/9214/9215/9216/9217/9218/9219/9210/921D/ 921E/921F/921K/921L/UNR921M/921N/921AJ/921BJ/921CJ

Silicon NPN epitaxial planer transistor

For digital circuits

Features

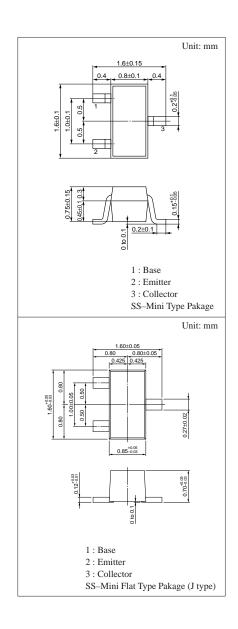
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- SS-Mini type package, allowing automatic insertion through tape packing and magazine packing.

Resistance by Part Number

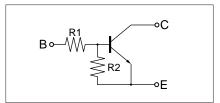
		Marking Symbol	(R_1)	(R_2)
•	UN9211	8A	$10k\Omega$	$10k\Omega$
•	UN9212	8B	$22k\Omega$	$22k\Omega$
•	UN9213	8C	$47 \mathrm{k}\Omega$	$47 \mathrm{k}\Omega$
•	UN9214	8D	$10k\Omega$	$47 \mathrm{k}\Omega$
•	UN9215	8E	$10k\Omega$	_
•	UN9216	8F	$4.7 \mathrm{k}\Omega$	_
•	UN9217	8H	$22k\Omega$	_
•	UN9218	81	$0.51 \mathrm{k}\Omega$	$5.1 \mathrm{k}\Omega$
•	UN9219	8K	$1k\Omega$	$10k\Omega$
•	UN9210	8L	$47 \mathrm{k}\Omega$	_
•	UN921D	8M	$47 \mathrm{k}\Omega$	$10k\Omega$
•	UN921E	8N	$47 \mathrm{k}\Omega$	$22k\Omega$
•	UN921F	80	$4.7 \mathrm{k}\Omega$	$10k\Omega$
•	UN921K	8P	$10k\Omega$	$4.7 \mathrm{k}\Omega$
•	UN921L	8Q	$4.7 \mathrm{k}\Omega$	$4.7 \mathrm{k}\Omega$
•	UNR9211	M EL	$2.2k\Omega$	$47 \mathrm{k}\Omega$
•	UNR9211	N EX	$4.7 \mathrm{k}\Omega$	$47 \mathrm{k}\Omega$
•	UNR921	AJ 8X	$100 \mathrm{k}\Omega$	$100 \mathrm{k}\Omega$
•	UNR9211	3J 8Y	$100 \mathrm{k}\Omega$	_
•	UNR9210	CJ 8Z		$47 \mathrm{k}\Omega$

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V_{CBO}	50	V	
Collector to emitter voltage	V _{CEO}	50	V	
Collector current	I_C	100	mA	
Total power dissipation	P_{T}	125	mW	
Junction temperature	T_{j}	125	°C	
Storage temperature	T_{stg}	-55 to +125	°C	



Internal Connection



Transistors with built-in Resistor 921E/921F/921K/921L/UNR921M/921N/921AJ/921BJ/921CJ

■ Electrical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current		I_{CBO}	$V_{CB} = 50V, I_E = 0$			0.1	μΑ
		I _{CEO}	$V_{CE} = 50V, I_{B} = 0$			0.5	μΑ
	UN9211		$V_{EB} = 6V, I_{C} = 0$			0.5	
	UN9212/9214/921E/921D					0.2	
Emitter	UN9213/UNR921M/921N/UNR921AJ	I_{EBO}				0.1	
cutoff	UN9215/9216/9217/9210/UNR921BJ					0.01	mA
current	UN921F/921K					1.0	
	UN9219					1.5	
	UN9218/921L/UNR921CJ					2.0	
Collecto	r to base voltage	V _{CBO}	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	50			V
Collecto	r to emitter voltage	V _{CEO}	$I_C = 2mA, I_B = 0$	50			V
	UN9211		$V_{CE} = 10V$, $I_C = 5mA$	35			
	UN9212/921E			60			
Forward	UN9213/9214/921M/UNR921AJ/921CJ			80			
current transfer	UN9215*/9216*/9217*/9210*/UNR921BJ			160		460	
ratio	UN921F/921D/9219			30			
	UN9218/921K/921L			20			
	UN921N			80		400	
Collector to emitter saturation voltage		V _{CE(sat)}	$I_C = 10 \text{mA}, I_B = 0.3 \text{mA}$			0.25	V
Output voltage high level		V _{OH}	$V_{CC} = 5V, V_{B} = 0.5V, R_{L} = 1k\Omega$	4.9			V
Output voltage low level			$V_{CC} = 5V, V_B = 2.5V, R_L = 1k\Omega$			0.2	
	UN9213/921K/UNR921BJ		$V_{OC} = 5V, V_B = 3.5V, R_1 = 1k\Omega$			0.2	
	UN921D	V _{OL}	$V_{CC} = 5V, V_B = 10V, R_1 = 1k\Omega$			0.2	V
	UN921E		$V_{CC} = 5V$, $V_B = 6V$, $R_L = 1k\Omega$			0.2	
	UNR921AJ		$V_{CC} = 5V$, $V_B = 5V$, $R_L = 1k\Omega$			0.2	
Transition frequency		f_T	$V_{CB} = 10V, I_E = -2mA, f = 200MHz$		150		MHz
	UN9211/9214/9215/921K	R_1			10		
	UN9212/9217				22		
Input	UN9213/921D/921E/9210				47		
resis-	UN9216/921F/921L/UNR921N			(-30%)	4.7	(+30%)	kΩ
tance	UN9218				0.51		
	UN9219/UNR921M				1		
	UNR921AJ/921BJ				100		

* h_{FE} rank classification (UN9215/9216/9217/9210)

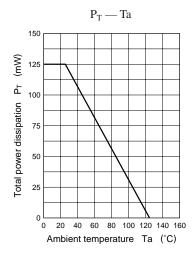
Rank	Q	R	S		
h_{FE}	160 to 260	210 to 340	290 to 460		

Transistors with built-in Resistor 921E/921F/921K/921L/UNR921M/921N/921AJ/921BJ/921CJ

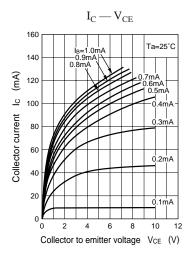
■ Electrical Characteristics (continued) (Ta=25°C)

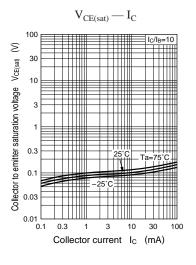
Parameter		Symbol	Conditions	min	typ	max	Unit	
	UN9211/9212/9	9213/921L			0.8	1.0	1.2	
	UN9214 UN9218/9219 UN921D				0.17	0.21	0.25	
					0.08	0.1	0.12	
						4.7		
Resis-	UN921E					2.14		
tance ratio	UN921F	UN921F		R_1/R_2		0. 47		
rado	UN921K				2.13			
	UN921M					0.047		
	UN921N UNR921AJ					0.1		
						1.0		
Resistance between Emitter to Base UNR921CJ		R ₂		-30%	47	30%	kΩ	

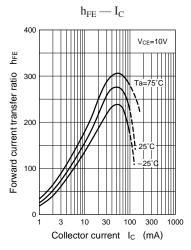
Common characteristics chart

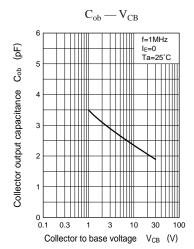


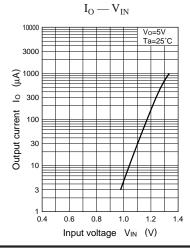
Characteristics charts of UN9211

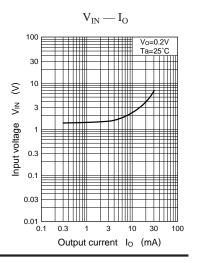


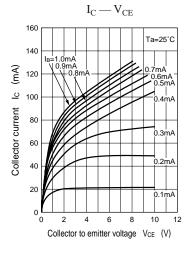


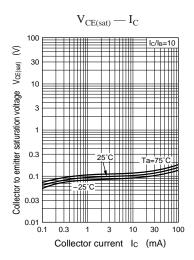


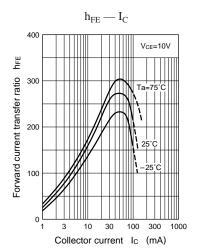


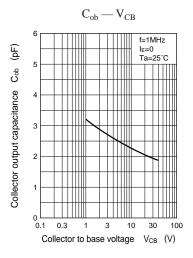


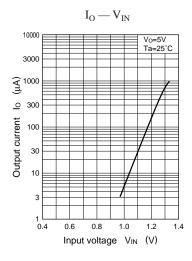


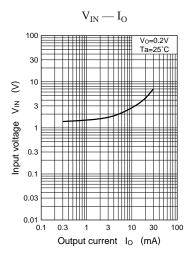




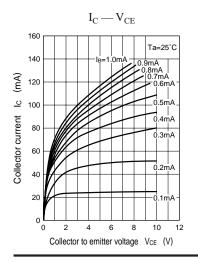


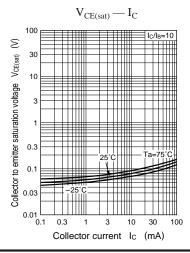


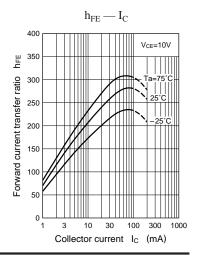


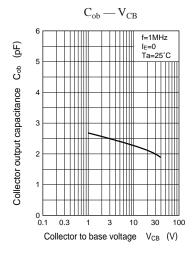


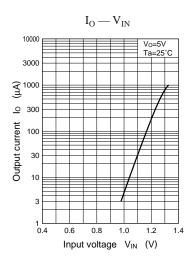
Characteristics charts of UN9213

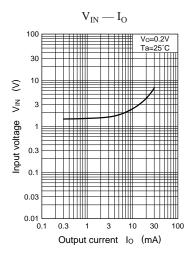


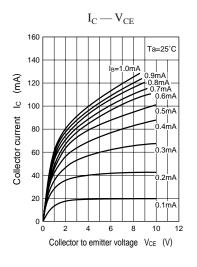


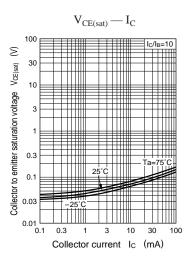


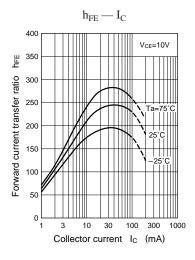


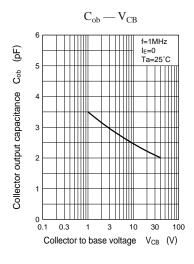


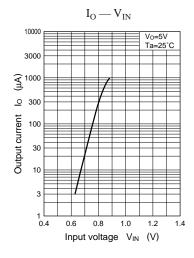


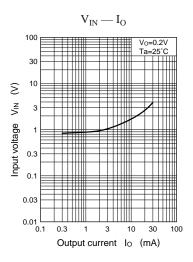


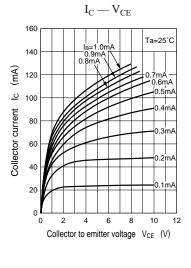


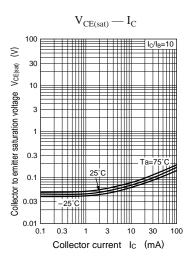


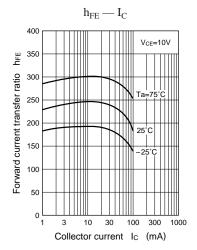


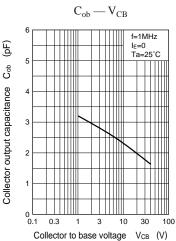


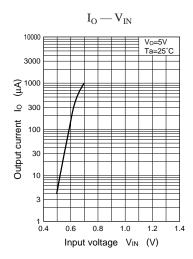


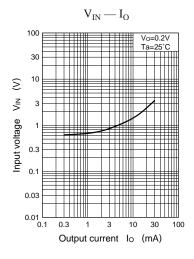




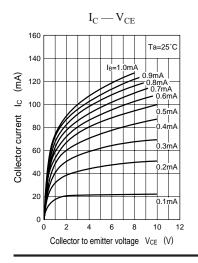


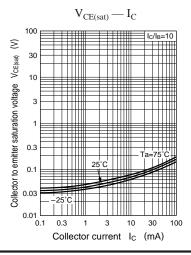


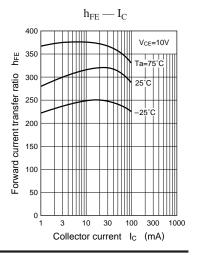


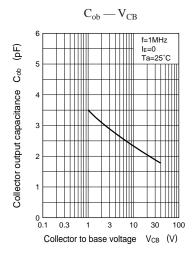


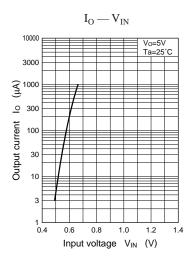
Characteristics charts of UN9216

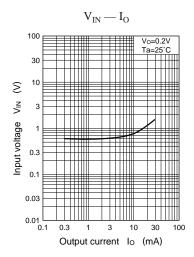


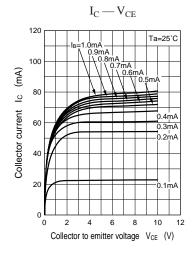


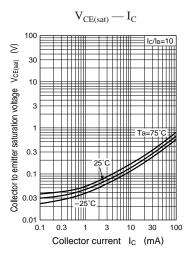


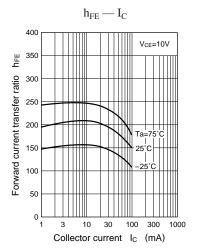


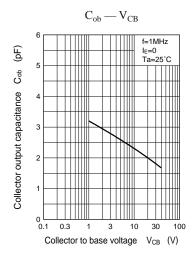


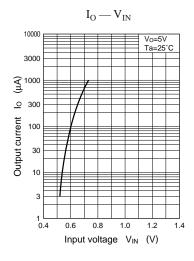


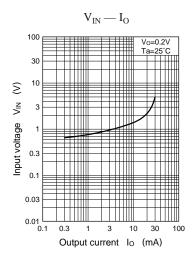


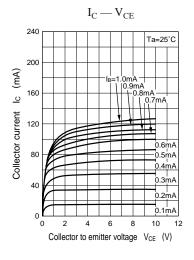


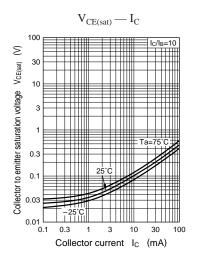


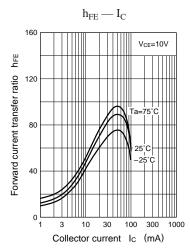


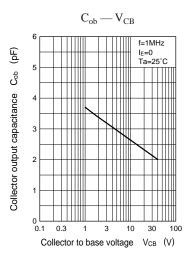


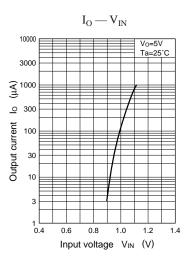


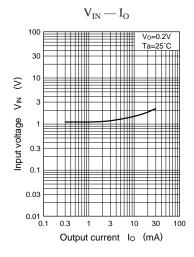




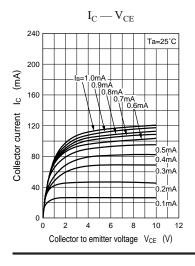


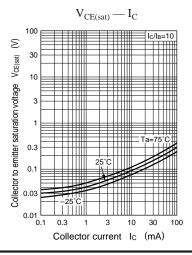


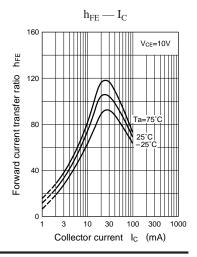


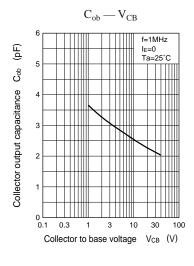


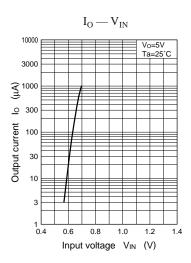
Characteristics charts of UN9219

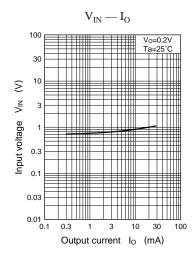


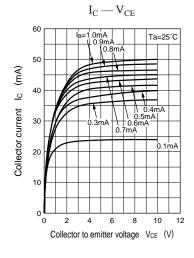


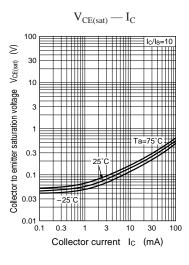


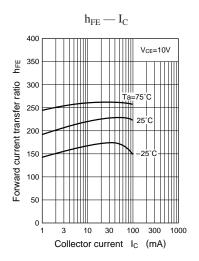


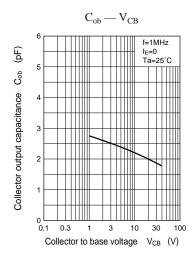


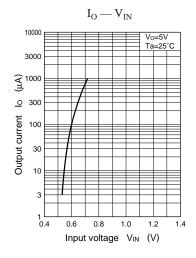


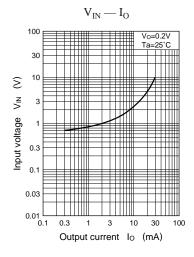


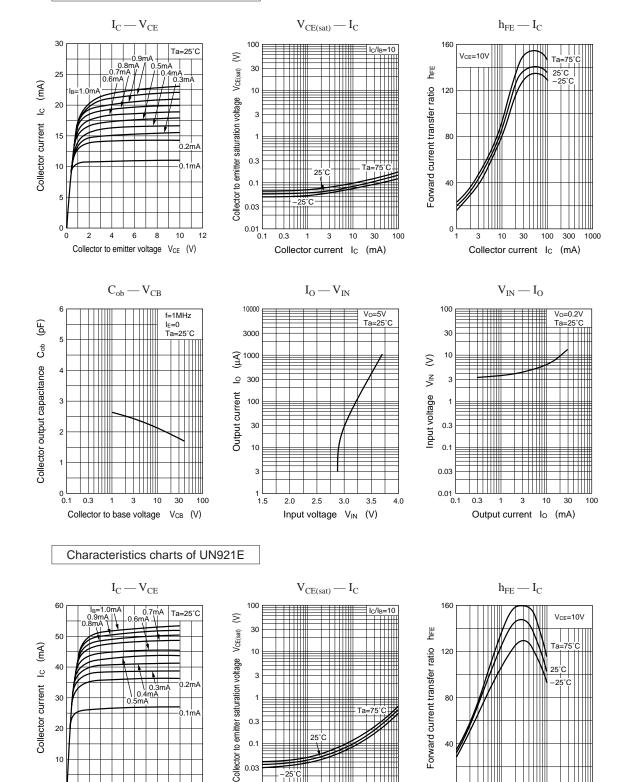












Collector current Ic

3 10 30

(mA)

0

30

Collector current Ic (mA)

10

0.1

0.03 0.01 L 0.1

0.3

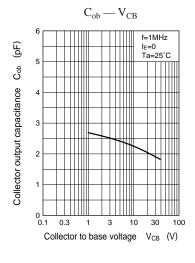
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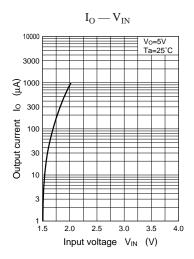
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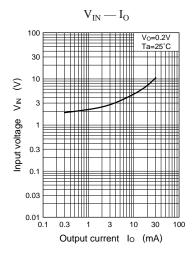
Collector to emitter voltage $\ V_{CE}\ (V)$

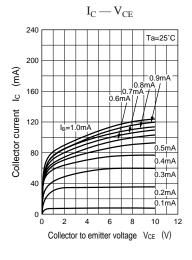
8 10 12 300 1000

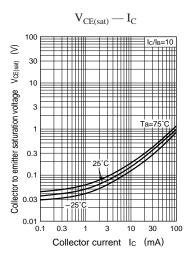
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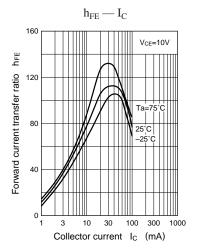


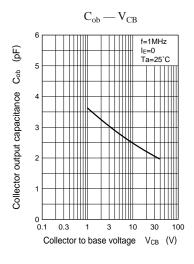


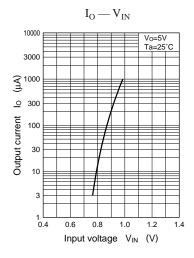


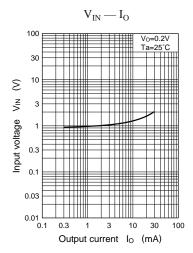


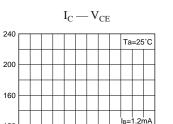












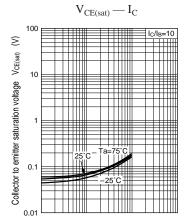
1.0mA 0.8mA

0.6mA

10 12

Collector current Ic (mA)

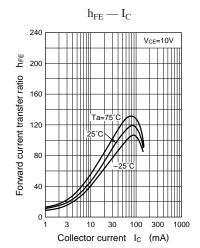
80

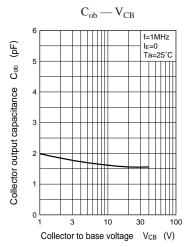


30

(mA)

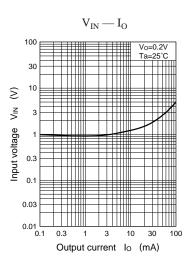
Collector current Ic





4 6

Collector to emitter voltage VCE (V)



Characteristics charts of UN921L

